

L Number	Hits	Search Text	DB	Time stamp
1	520584	semiconductor or substrate	USPAT	2003/01/04 13:47
2	177753	semiconductor adj substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/01/04 13:48
3	13869	(semiconductor adj substrate) and chamber	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/01/04 13:48
4	980	((semiconductor adj substrate) and chamber) and (reservoir or tank)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/01/04 13:48
5	184	((semiconductor adj substrate) and chamber) and (reservoir or tank)) and controller and valve	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/01/04 14:04
6	5390	(165/47,48.1,58,61,63,64,80.1,80.2,80.3,80. USPAT 5).CCI	USPAT	2003/01/04 14:05
7	5	((165/47,48.1,58,61,63,64,80.1,80.2,80.3,80. USPAT 5).CCI	USPAT	2003/01/04 14:38
8	519	and substrate and chamber and (tank or reservoir) and valve and controller subramanian.in.	USPAT	2003/01/04 14:39
9	1179	subramanian.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/01/04 14:43
10	307	subramanian.in. and (semiconductor or resist)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/01/04 14:44